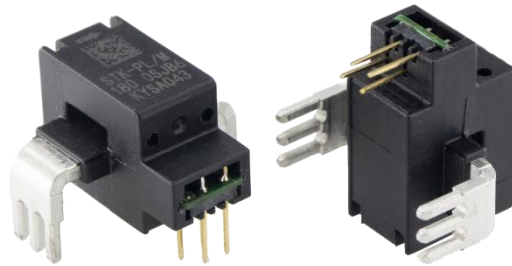


Current Sensor

Product Series: STK-PL/M

Part number: STK-80PL/M
STK-100PL/M
STK-120PL/M
STK-150PL/M
STK-180PL/M

Version: Ver1.1



Sinomags Technology Co., Ltd

Web site: www.sinomags.com

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1. Summary

The STK-PL/M series is based on hall (Tunneling-Magnetoresistance) technology and open-loop design. It is suitable for DC, AC, pulsed and any kind of irregular current measurement under the isolated conditions. The nominal current range of the STK-PL/M current sensor consists of 80A,100A,120A, 150A,180A.

Typical applications

- PV combiner box
- PV inverter (MPPT & AC)
- motor driver controller
- SMPS & UPS
- Battery management system

Standards

- EN50178:1997
- IEC 61010-1:2010
- IEC 61326-1:2012

General parameter

Parameter	Symbol	Unit	Value
Working temperature	T _A	℃	-40 ~ 105
Storage temperature	T _{stg}	℃	-40 ~ 105
Mass	m	g	10

Absolute maximum rating

Parameter	Symbol	Unit	Value
Supply voltage (non-destructive)	V _C	V	6.0
ESD rating (HBM)	U _{ESD}	kV	4
ESD rating (CDM)	U _{CDM}	kV	1.5

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

Ratings

Parameter	Symbol	Unit	Value
Primary involved potential		V AC/DC	600
Ambient operating temperature	T_A	°C	105
Primary current	I_p	A	According to series primary current
Secondary supply voltage	U_c	V DC	5
Output voltage	V_out	V	0.1 ~ 4.9

Isolation parameter

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC test 50Hz/1 min	U _d	kV	5	
Impulse withstand voltage 1.2/50μs	Ū _w	kV	8	
Clearance distance (pri. -sec)	d _{Cl}	mm	8	Shortest distance through air
Creepage distance (pri. -sec)	d _{Cp}	mm	8	Shortest path along device body
Case material			V0 according to UL 94	
Application example		V	600	Reinforced insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1000	Basic insulation, CAT III, PD 2, non uniform field according EN 50178, IEC 61010
Application example		V	1500	Basic insulation, CAT III, PD 2, according to IEC 62109-1 Altitude ≤ 3000 m
Application example		V	600	CAT III, PD 2, according to UL 508

2. STK-80PL/M Electrical performance

Condition: $T_A = 25^{\circ}\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		80		
Primary current measuring range	I_{pm}	A	-200		200	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		10		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Rated linearity error	Non- L_{pn}	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non- L_{pm}	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.5		@ 10% of I_{pn}
Step response time	t_{res}	μs		1		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		500 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		500		No RC circuit
Output voltage noise DC ~ 10 kHz DC ~ 100 kHz	V_{noise}	mVpp		10 15		
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$

3. STK-100PL/M Electrical performance

Condition: $T_A = 25^{\circ}\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		100		
Primary current measuring range	I_{pm}	A	-250		250	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		8		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Rated linearity error	Non- L_{pn}	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non- L_{pm}	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.5		@ 10% of I_{pn}
Step response time	t_{res}	μs		1		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		500 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		500		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$

4. STK-120PL/M Electrical performance

Condition: $T_A = 25^{\circ}\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		120		
Primary current measuring range	I_{pm}	A	-300		300	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		6.667		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Rated linearity error	Non- L_{pn}	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non- L_{pm}	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.5		@ 10% of I_{pn}
Step response time	t_{res}	μs		1		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		500 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		500		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$

5. STK-150PL/M Electrical performance

Condition: $T_A = 25^{\circ}\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

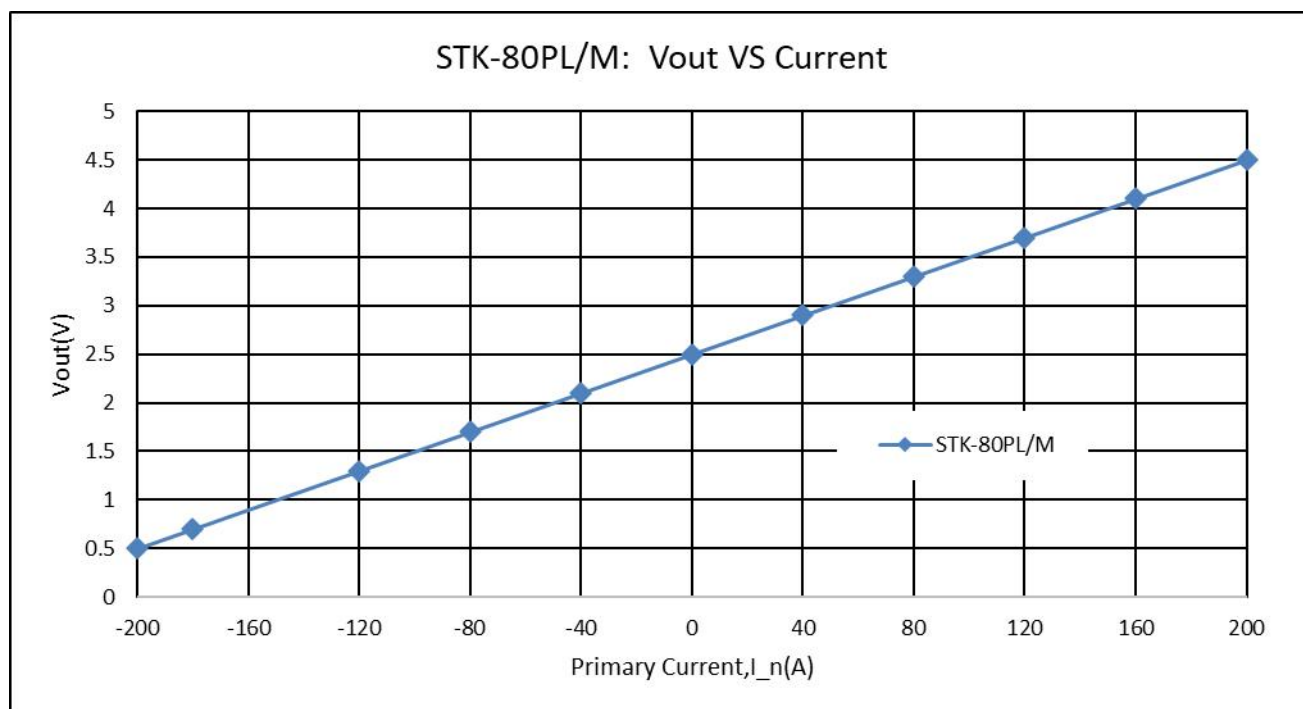
Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		150		
Primary current measuring range	I_{pm}	A	-375		375	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		5.333		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Rated linearity error	Non- L_{pn}	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	Non- L_{pm}	% I_{pm}	-3		3	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.5		@ 10% of I_{pn}
Step response time	t_{res}	μs		1		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		500 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		500		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$

6. STK-180PL/M Electrical performance

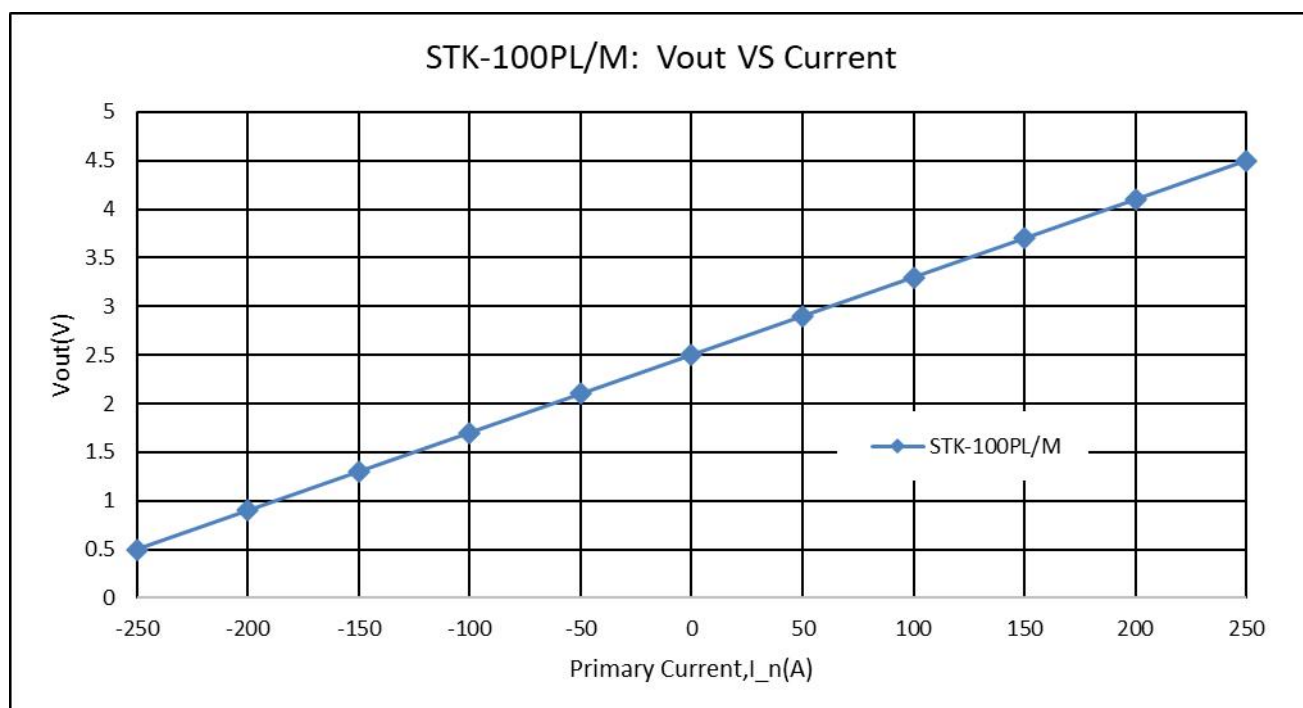
Condition: $T_A = 25^{\circ}\text{C}$ $V_{CC} = 5\text{ V}$ (Except special instructions)

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal current rms	I_{pn}	A		180		
Primary current measuring range	I_{pm}	A	-450		450	
Supply voltage	V_{CC}	V	4.75	5	5.25	
Current consumption	I_{CC}	mA		5	10	
Reference voltage	V_{ref}	V	2.48	2.5	2.52	Output function
Rated output voltage	V_{FS}	V		0.8		$(V_{out} - V_{ref}) @ I_{pn}$
Internal output resistance	R_{out}	Ω		1		Output
Quiescent voltage	V_{off}	V	2.48	2.5	2.52	$V_{out} @ 0\text{ A}$
Electrical offset voltage	V_{oe}	mV	-10		10	$(V_{out} - V_{ref}) @ 0\text{ A}$
Temperature drift of V_{oe}	V_{oe_TRange}	% V_{FS}	-1.5		1.5	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Magnetic offset current	I_{om}	A	-0.25		0.25	@ $\pm 10 \times I_{pn}$
Theoretical gain	G_{th}	mV/A		4.444		800 mV @ I_{pn}
Error of gain	Err_G	% G_{th}		± 1		Trimmed in the factory @ 25°C
Temperature drift of gain	G_{TR}	% G_{th}	-1.0		1.0	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$
Rated linearity error	$Non-L_{pn}$	% I_{pn}	-0.5		0.5	$\pm I_{pn}$
Linearity error @ I_{pm}	$Non-L_{pm}$	% I_{pm}	-5		5	$\pm I_{pm}$
Reaction time	t_{ra}	μs		0.5		@ 10% of I_{pn}
Step response time	t_{res}	μs		1		@ 90% of I_{pn}
Delay time	t_{delay}	μs		0.8		500 kHz sine wave
Frequency bandwidth (-3dB)	BW	kHz		500		No RC circuit
Output voltage noise	V_{noise}	mVpp		10		
DC ~ 10 kHz						
DC ~ 100 kHz						
Accuracy @ 25°C	X	% of I_{pn}	-1		1	@ 25°C
Accuracy @ $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$	X_{TRange}	% of I_{pn}	-2		2	$-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$

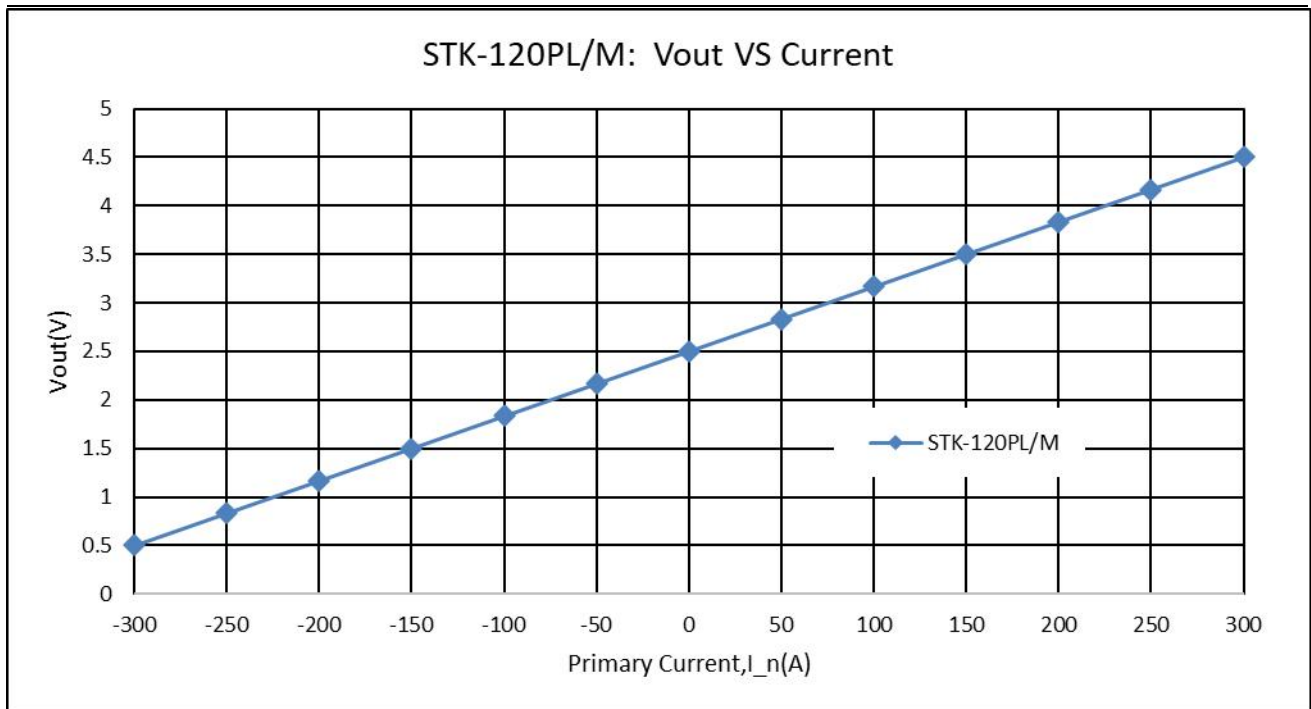
7. Output voltage VS primary current



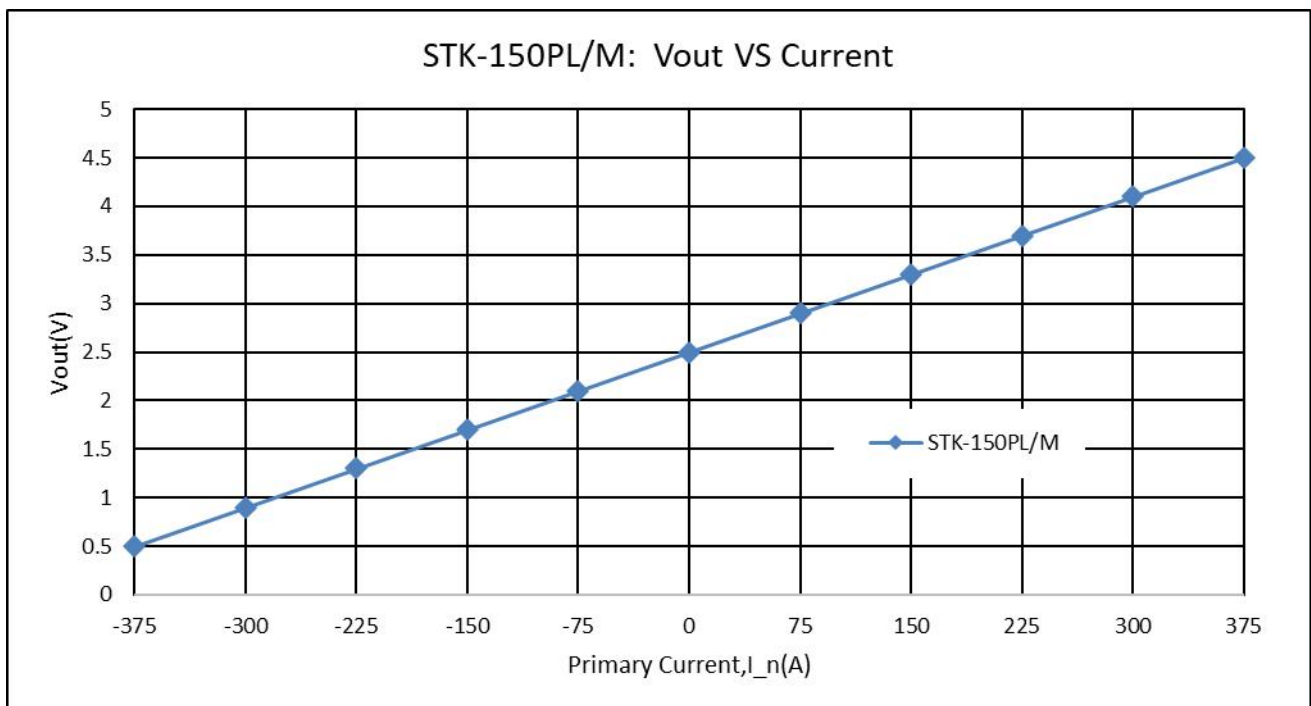
The dependence of Vout of STK-80PL/M on the primary current.



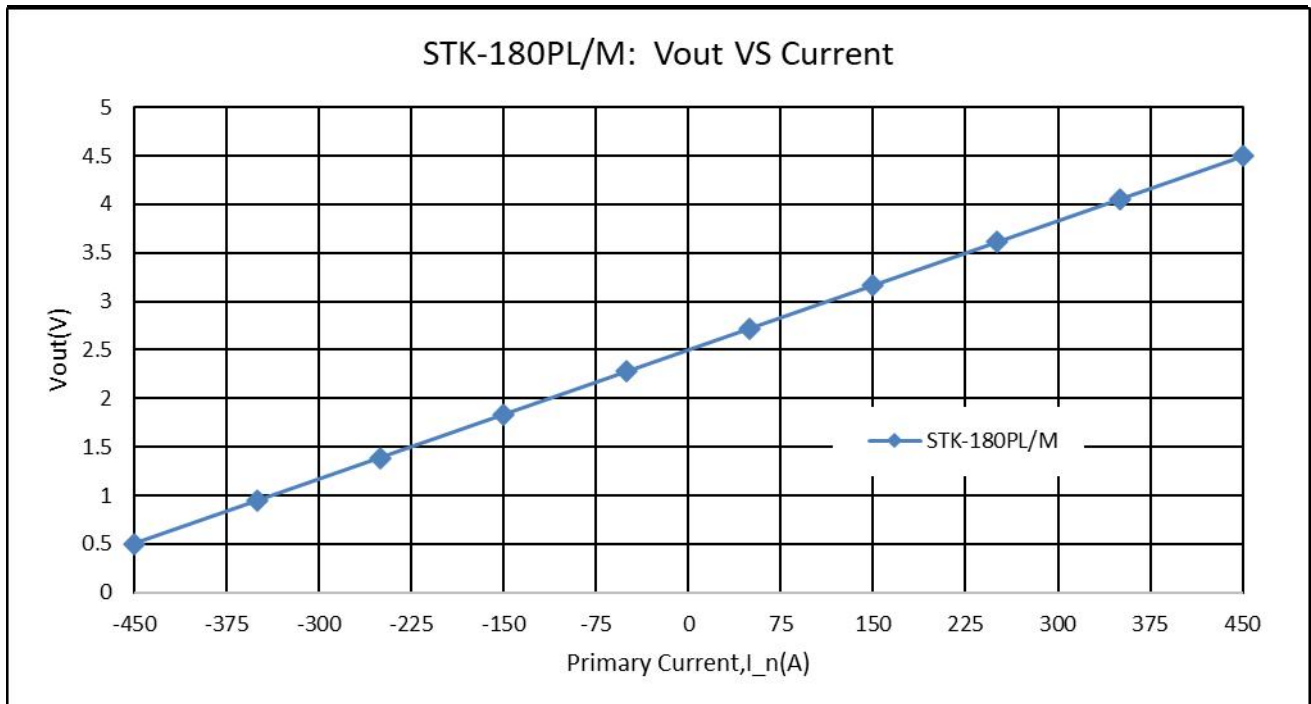
The dependence of Vout of STK-100PL/M on the primary current.



The dependence of Vout of STK-120PL/M on the primary current.

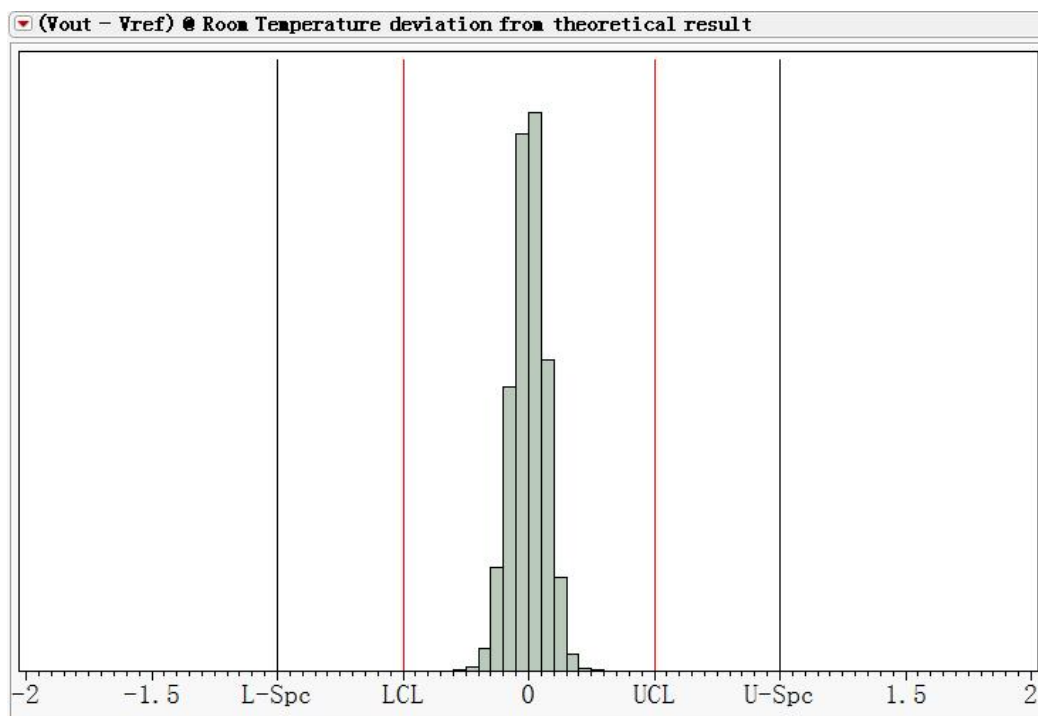


The dependence of Vout of STK-150PL/M on the primary current.



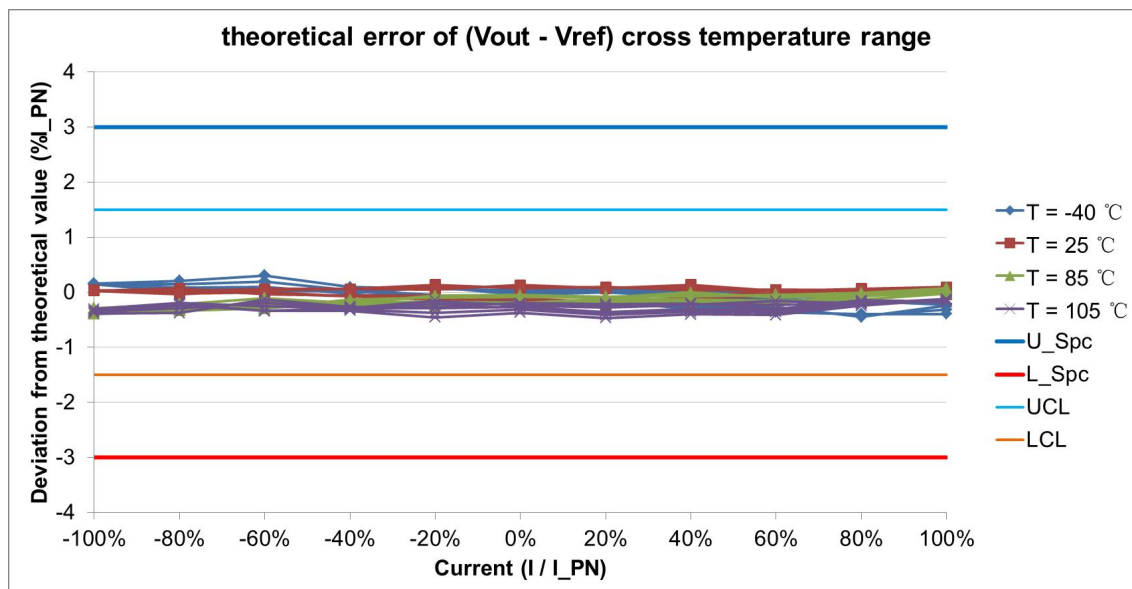
The dependence of Vout of STK-180PL/M on the primary current.

8. Accuracy characteristics in room temperature

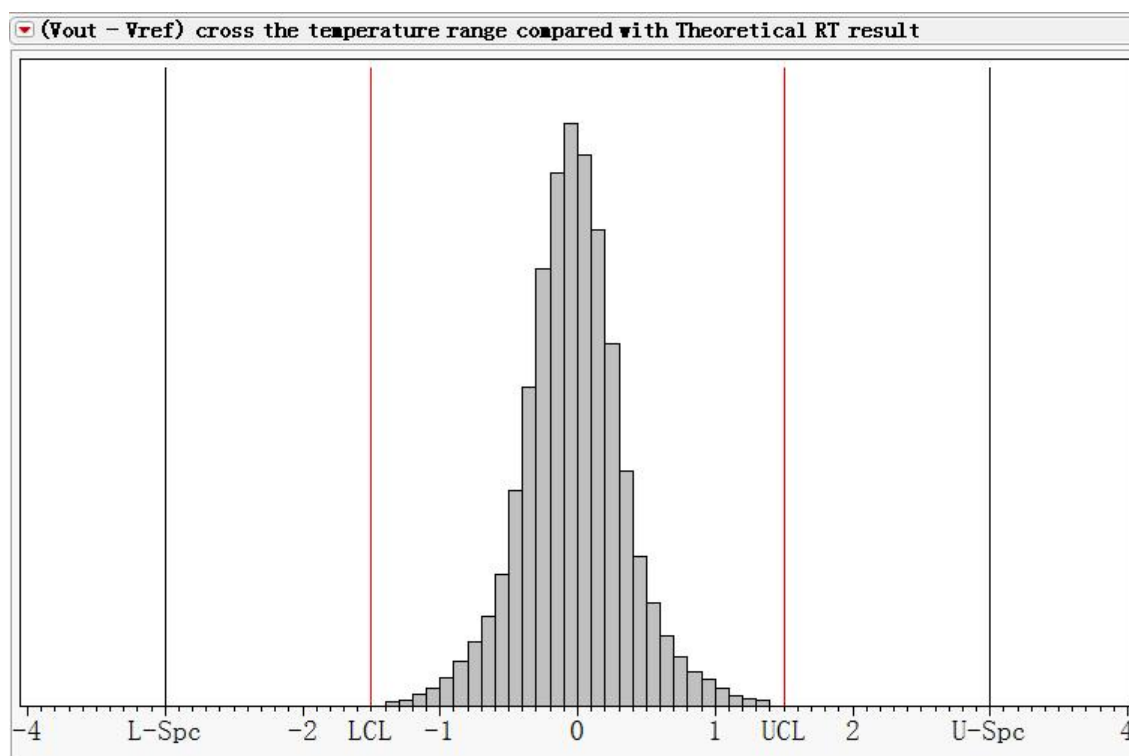


The error of STK-PL/M current sensor at 25 °C compared with the standard output , $((V_{out} - V_{ref})_{measure} @ I_n @ 25^{\circ}C - V_{oe}@25^{\circ}C - G_{th} * I_n) / V_{FS}$. Vout represents voltage of Vout, Vref the voltage of Vref, I_n the primary current, V_{oe} the (Vout - Vref)@0A, G_{th} the theoretical gain, V_{FS} the rated output voltage.

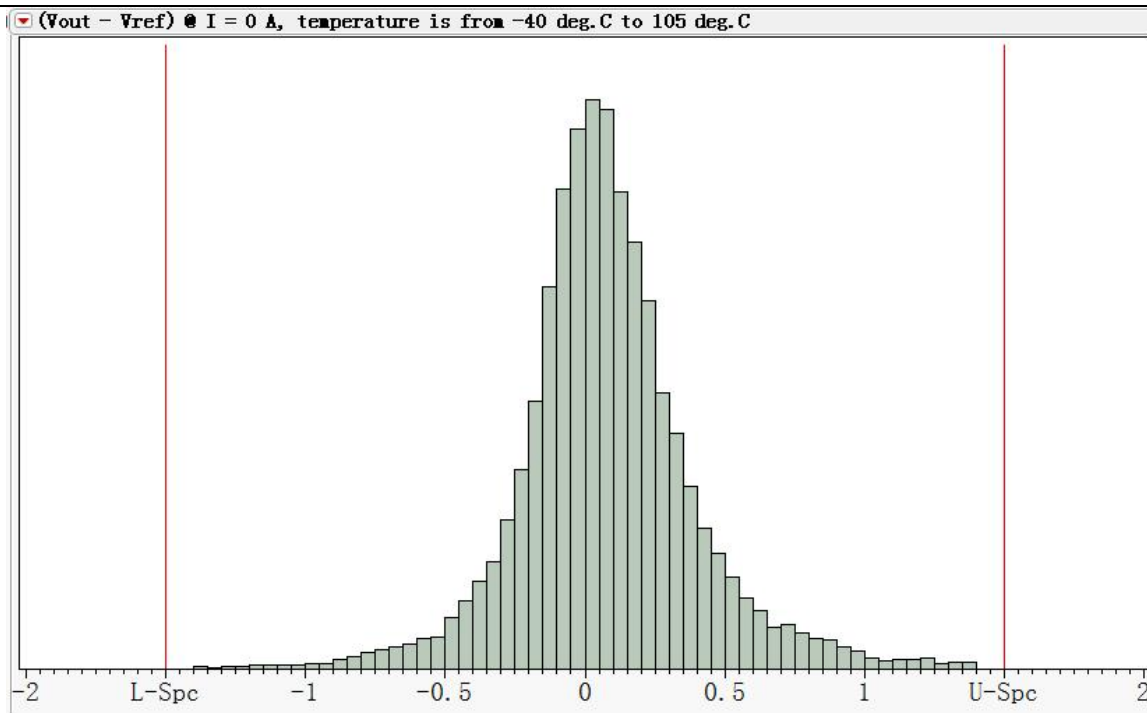
9. Accuracy cross temperature



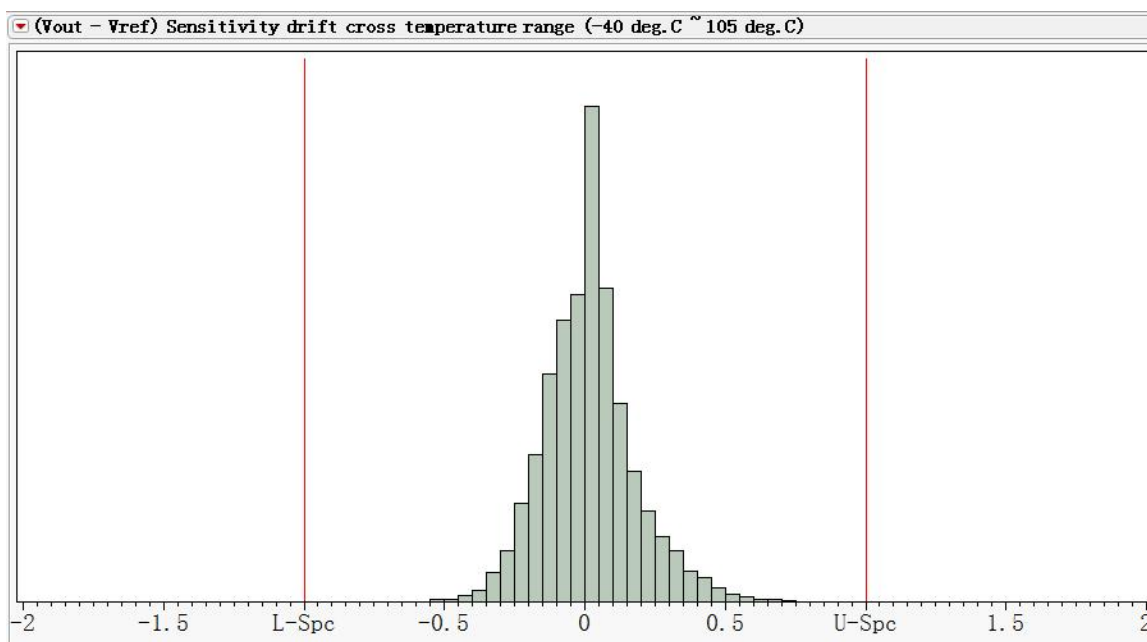
The error of STK-PL/M current sensor at $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$ compared with the standard output at room temperature, $((V_{\text{out}} - V_{\text{ref}})_{\text{measure}} @ I_n @ T_x - V_{\text{oe}} @ T_x - G_{\text{th}} * I_n) / V_{\text{FS}}$. Where, V_{out} represents voltage of V_{out} , V_{ref} the voltage of V_{ref} , I_n the primary current, T_x the present temperature, V_{oe} the $(V_{\text{out}} - V_{\text{ref}}) @ 0\text{A}$, G_{th} the theoretical gain, V_{FS} the rated output voltage.



The error of STK-PL/M output $(V_{\text{out}} - V_{\text{ref}})$ current sensor at $-40^{\circ}\text{C} \sim 105^{\circ}\text{C}$ compared with the standard output $(V = G_{\text{th}} * I_n)$, $((V_{\text{out}} - V_{\text{ref}}) @ I_n @ T_x - G_{\text{th}} * I_n) / V_{\text{FS}}$, Where, I_n represents present primary current, T_x the present temperature, G_{th} the theoretical gain, V_{FS} the rated output voltage.

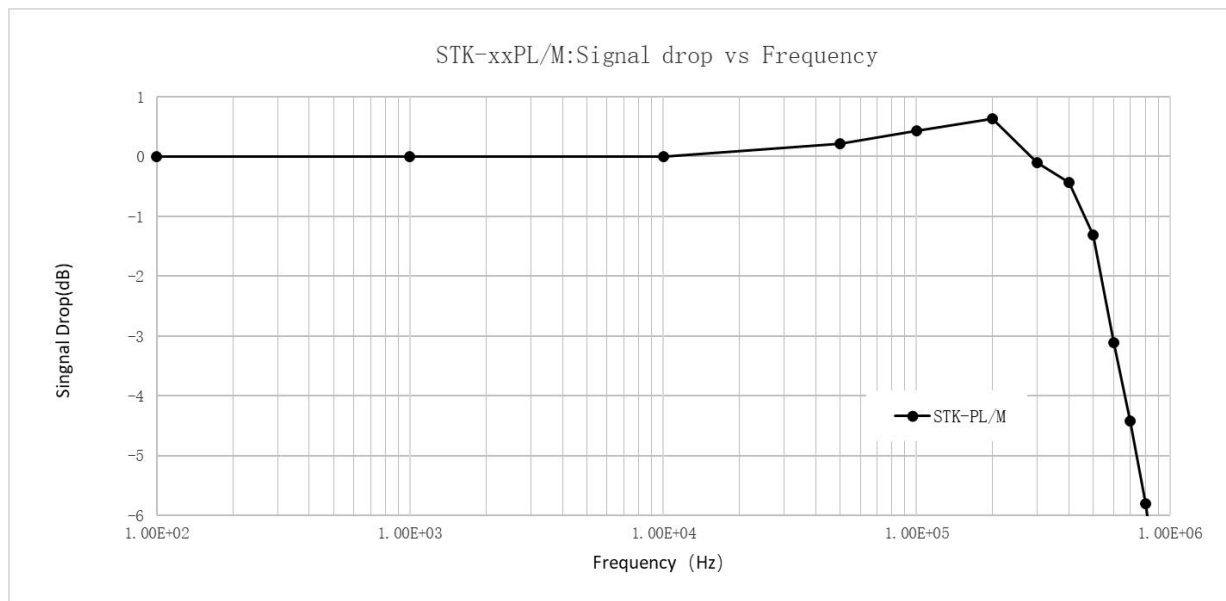


Temperature drift of Voe, $V_{oe_TRange} = (V_{oe} @ T_x - V_{oe} @ 25^{\circ}\text{C}) / V_{FS}$. T_x represents present temperature, V_{FS} the rated output voltage.



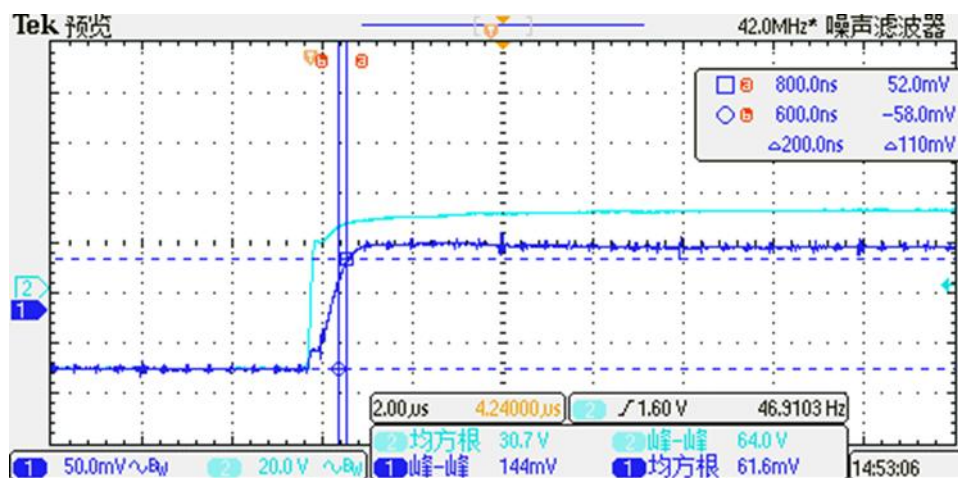
Error of gain, $Err_G = (((V_{out} - V_{ref}) @ I_{pn} - (V_{out} - V_{ref}) @ (-I_{pn})) / 2) - V_{FS} / V_{FS}$. Where I_{pn} represents the rated current, $-I_{pn}$ the reversed rated current.

10. Frequency response and bandwidth



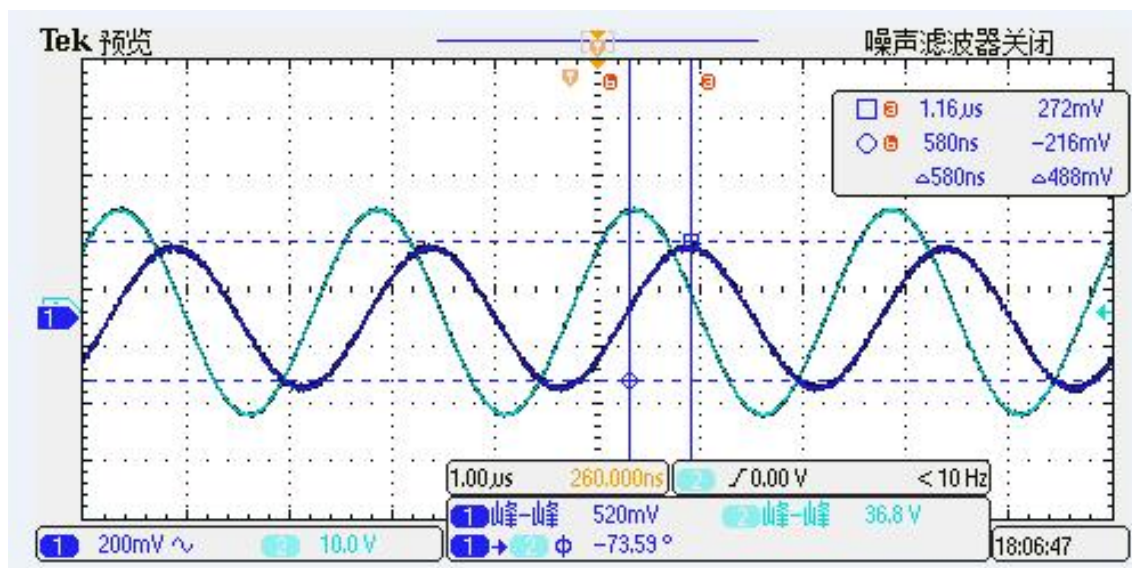
The frequency bandwidth of STK-xxPL/M series current sensor. The bandwidth of current sensor is DC ~ 500 kHz (-3dB).

11. Step response time



The typical frequency response of STK-xxPL/M current sensor. The response time from 90% of the primary current (light blue) to 90% of the secondary output (dark blue) is less than 1 μs

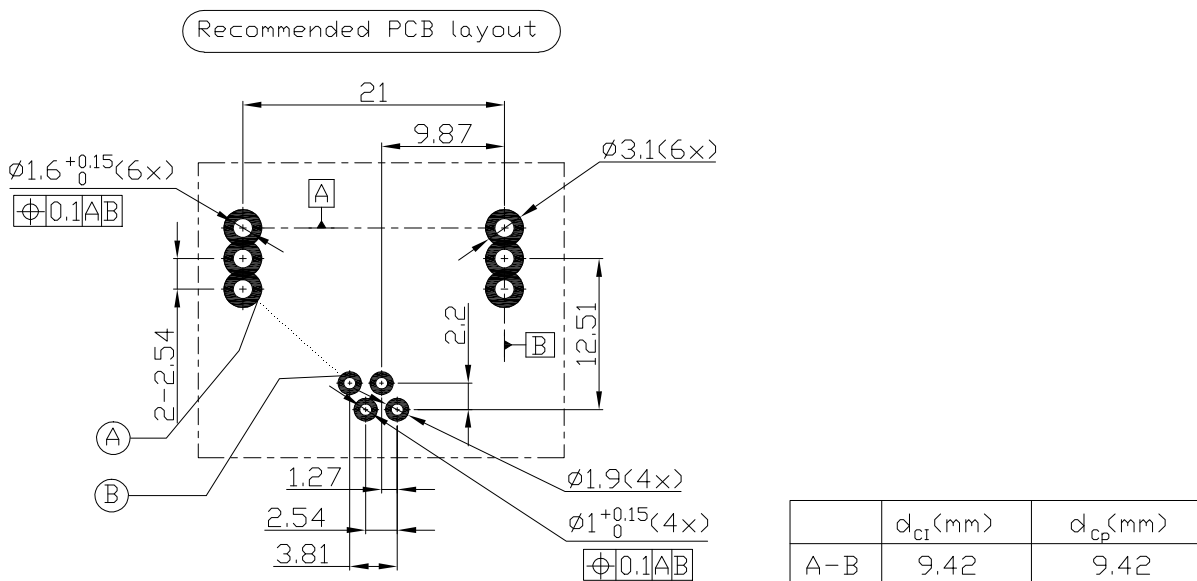
12. Frequency delay performance



When testing 500 kHz sine wave, the typical result of STK-xxPL/M current sensor's output. The response time from the primary current (light blue) to the secondary output (dark blue) is less than 0.8μ s.

13. Recommended PCB layout

Installation of view: overlooking (unit: mm)



1. Installing angle: Overlook (observe from the side of installing transducer)
2. Recommended bore diameter of primary current line, (diameter of primary current $\times 1.2$) mm
3. Recommended bore diameter of secondary current line, (diameter of secondary current $\times 1.2$) mm
4. The maximum thickness of PCB is 2.5 mm
5. The curve of wave soldering: $260^{\circ}\text{C} \times 10 \text{ s}$

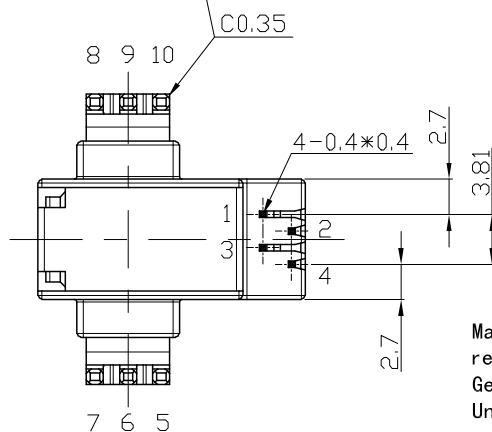
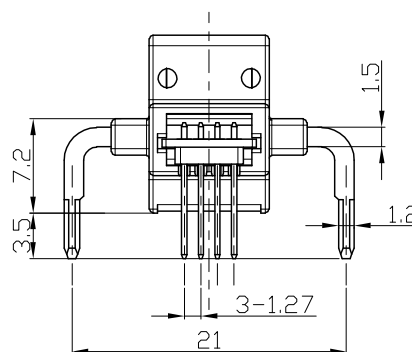
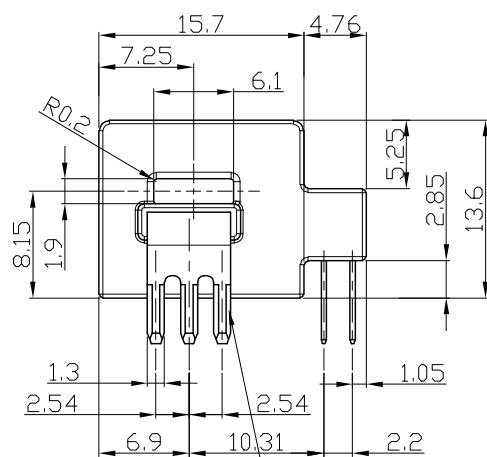
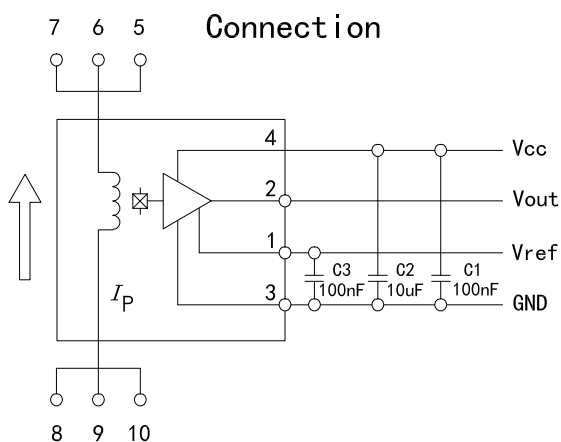
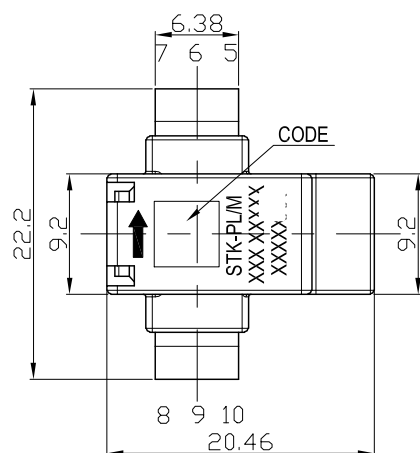


Security:

This current sensor must be used in limited-energy secondary circuit according to IEC 61010-1.

- This current sensor must be used in electric/electronic equipment with respect to appliance standards and safety requirement in accordance with the manufacture's operating instructions;
- When operating the current sensor, certain parts of the module can carry hazardous voltage;
- Failure to wiring as shown in the diagram will damage the current sensor;
- Ignoring this warning can lead to serious consequences.
- A protective housing or a additional shield could be used.
- Main supply must be able to disconnected.

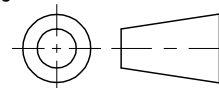
14. Dimension & Pin definitions



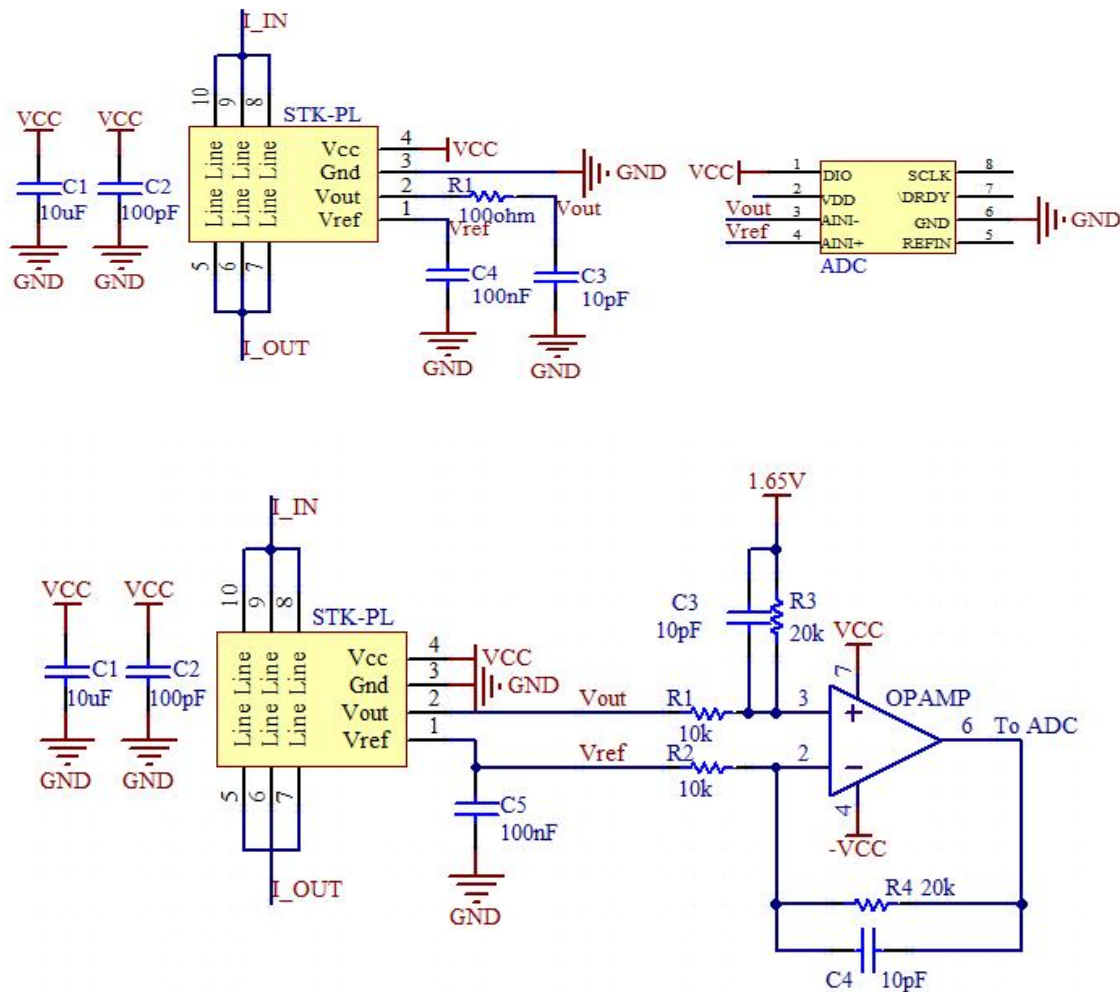
Terminal Pin Identification

- 1 : V_{ref}
- 2 : V_{out}
- 3 : GND
- 4 : V_{cc}
- 5, 6, 7 : Primary input Current (-)
- 8, 9, 10 : Primary input Current (+)

Material : Fit UL94V-0 & RoHS requirements ;
 General tolerance : ± 0.5
 Unit : mm



15. Appendix: typical application circuit



R3 (kohm)	C3 (nF)	Theoretical -3dB $f = 1/(2\pi RC)$ (kHz)	Measured -3dB (kHz)
20	20	498	~500
20	81	98	~ 100
20	810	10	~ 10

The frequency characteristics of STK-xxPL/M series current sensor are not affected by the R-C setting (according to recommended R-C setting), therefore the active filter circuit or R-C circuit can be applied to modulate the sensor's frequency characteristics.

The signal input to ADC is $1.65 + R4/R2 \cdot (Vout - Vref)$ with the conditions: $R1 = R2$, $R3 = R4$, $C3 = C4$.